PCN Number:			20160119001						PCN Date:	01/25	5/2016	5				
Title: Qualification Devices		of UTAC as Additional Assembly and Test Site for Select PQFN Package														
Customer Contact:			PC	N Mana	ger	De	pt:		Quality	Se	rvio	vices				
Proposed 1 st Ship Date			e:			16		timated Sample D		Dat	Date Provided at Sample equest					
Char	nge Ty	ype:														
Assembly Site					Design				Wafer Bum	p Site						
		nbly Pr				Data Sheet				Ħ	Wafer Bump Material					
			aterials			Part number change				Ħ	Wafer Bum					
H			Specific		on .		_	st Site		larige		Ħ	Wafer Fab Site			
X			pping/L					st Proces	:5			Ħ	Wafer Fab		als	
	Tucki	119/ 5111	ppilig/ L	.ubc	Jiirig		10.	30 1 10000				Ħ	Wafer Fab Process			
							D	CN Dai	to:I	le .			_ Waler Fab Process			
D			NI	_			<u> </u>	CN Det	Lall	5						
			Change					,		· c· · · ·			O A 1 1111			
													C as Addition			
								"Product	t Afi	rected" S	ect	ion	. Current as	sembly	sites	
and I	Materi	al diffe	rences	are	as fol	lows.	•								-	
Ass	embly	Site	Assemb	bly Site Origin			gin Assembly Country		y Code A		As	Assembly Site City		j		
TI	Malay	sia		MLA			MY				Kuala Lumpur					
	UTAC			NSE				TH				Bangkok				
						· ·				<u> </u>					1	
Material Differences:																
					TI M	alay	sia			UTAC						
Mount Compound						5846		PZ0035				1				
		finish		NiPdA						PdAuAg		=				
	LCGC	4 11111311	<u> </u>			1 47 (4		i		ii urturtg			1			
	Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.								1							
Reason for Change:																
Continuity of supply.																
Anti	cipate	ed imp	act on	Fo	rm, Fi	t, Fu	ınctio	on, Qual	ity	or Relia	bil	ity	(positive /	negat	ive):	
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): None																
Anticipated impact on Material Declaration																
□ No Impact to the □ Material Declarations or Product Content reports are driven from								ven fro	om							
Material Declaration			· ·													
				release. Upon production release the revised reports can be												
					obtained from the <u>TI ECO website</u> .											
Changes to product identification resulting from this PCN:																
As	sembl	ly Site														
TI-MALAYSIA				Assembly Site Origin (22L)				ASO: MLA								
UTAC				Assembly Site Origin (22L) ASO: NSE												
UIAC					ASSETTIBLY SILE OFIGHT (22L) ASO. NSL											

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q:

2DC: 2Q: MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

합. SPE : 5A (L)TO:1750

(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812

(2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

ASSEMBLY SITE CODES: TI-MALAYSIA = K , UTAC = J

Product Affected:

ASP00886IRGCR	MSP430F5326IRGCR	MSP430F5522IRGCT	MSP430V356IRGCR
ASP00886IRGCT	MSP430F5326IRGCT	MSP430F5524IRGCR	MSP430V357IRGCR
MSP430A132IRGCR	MSP430F5328IRGCR	MSP430F5524IRGCT	MSP430V375IRGCR
MSP430A133IRGCR	MSP430F5328IRGCT	MSP430F5526IRGCR	MSP430V390IRGCR
MSP430A134IRGCR	MSP430F5513IRGCR	MSP430F5526IRGCT	MSP430V397IRGCR
MSP430A145IRGCR	MSP430F5514IRGCR	MSP430F5528IRGCR	
MSP430F5324IRGCR	MSP430F5514IRGCT	MSP430F5528IRGCT	
MSP430F5324IRGCT	MSP430F5522IRGCR	MSP430V355IRGCR	

Qualification Report

UTAC VQFN transfer using MSP430F5528IRGC Qualification Approved on 1/13/2016

Product Attributes

Attributes	Qual Device: MSP430F5528IRGC	QBS Device #1: MSP430F5438AIPZ	QBS Device #2: MSP430F5529IPN
Assembly Site	UTAC	TAI	TAI
Package Family	QFN	LQFP	LQFP
Flammability Rating	UL94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Site	TSMC-WF11	TSMC-WF11	TSMC-WF11
Wafer Fab Process	TSMC 0.18um Embedded Flash	TSMC 0.18um Embedded Flash	TSMC 0.18um Embedded Flash

⁻ QBS: Qual By Similarity

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: MSP430F5528IRGC	QBS Device #1: MSP430F5438AIPZ	QBS Device #2: MSP430F5529IPN
HAST	HAST 110C / 85% RH	264 Hours	3/77/0	NA	NA
AC	Autoclave 121C, 100% RH,15PSI	96 Hours	3 / 231 / 0	NA	NA
TC	Temperature Cycle -65/150C	500 Cycles	3 / 231 / 0	NA	NA
HTSL	High Temperature Storage Life 170C	420 Hours	3 / 231 / 0	NA	NA
CDM	ESD - CDM	250V, 500*V	1/3/0	NA	NA
MQ	Manufacturability	Per Spec	Pass	NA	NA

⁻ Qual Device MSP430F5528IRGC is qualified at LEVEL2-260CG

НВМ	ESD - HBM	500V, 1000V, 2000*, 4000*V	QBS to #2	NA	1/3/0
HTOL	High Temperature Operating Life 150C	300 Hours	QBS to #1, #2	3 / 231 / 0	1/77/0
LU	Latch Up 25C	100mA	QBS to #2	NA	1/3/0
EDR	Endurance Test -40C	1E13 Cycles	QBS to #1	3 / 36 / 0	NA
EDR	Endurance Test 25C	1E13 Cycles	QBS to #1	3 / 36 / 0	NA
EDR	Endurance Test 85C	1E13 Cycles	QBS to #1	3 / 36 / 0	NA

^{*} Indicates read point extends beyond that for standard qualification. This is supplementary information only.

- Preconditioning was performed for HTOL, Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV:125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7 eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com